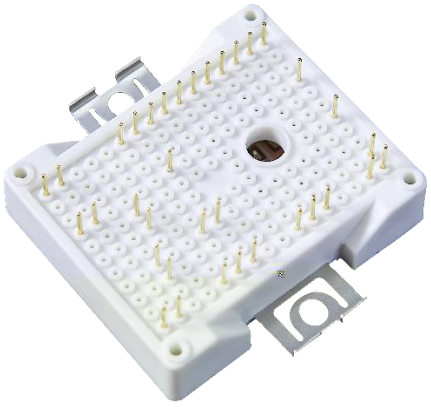
MG25P12P3

RoHS COMPLIANT



IGBT Modules

V_{CES} 1

I_C

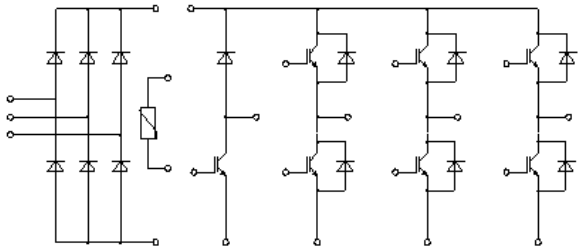
Applications

- (OM MQ MN
- I . MQ MQ H GA M
- 0+. 0I DOMP OE+G + R M P GN

Features

- R NRDOCDB GNN N
- R1 NORDC NQQ OH MPM ADDI O
- I GP DBANO N AOM QMT IOD MGGi2
- R D P OI N
- BCNC MO DMPO =DGT PN
- N GO C ONDF PNDB O Ci GBT
- (SBHPH EPI ODI OH MPM ℃

Circuit



● IGBT- inverter

Absolute Maximum Ratings

Parameter	Symbol	Conditions	Value	Unit
G OM HDOMI GB	1 .	1 1 H /E ℃		1
IODP PN G OM PMI O		/ ℃ TEH S= ℃		
- OQ + F G OM PMI O	-(	O HN		
O HDOMI GB	1 .	/E ℃	±	1
/ OG+ R M DND ODI	+OO	/ ℃ /EH S ℃		2

IGBT- inverter

Characteristic values

Parameter	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
O HDDM/OMNC G1 GB	1 C	1 1 H /E ℃				1
G OM HDDM PO AA PWMI O	.	1 11 1 /E ℃				H
G OM HDDM . OPMODI 1 GB	1 NO	1 1 /E ℃				1
		1 1 /E ℃				
		1 1 /E ℃				
O C MB	,					P
I PO DDI	DN	1 11 1 A (U/E ℃				I
- QMN /MINAM DDI	MN					I
O HDDMG F B PWMI O	.	1 11 1 /E ℃				I
/PM I GT/DH	O I	1 1 1 1 - /E ℃				IN
-DN /DH	QM					IN
/PM AA GT/DH	O AA					IN
GS/DH	QA					IN
I NBT DND ODI PMDB /PM I /DH	I					H
I NBT DND ODI PMDB /PM AA/DH	AA					H
/PM I GT/DH	O I	1 1 1 1 - /E ℃				IN
-DN /DH	QM					IN
/PM AA GT/DH	O AA					IN
GS/DH	QA					IN
I NBT DND ODI PMDB /PM I /DH	I					H
I NBT DND ODI PMDB /PM AA/DH	AA					H
. O	.	O PN1 1 /E ℃ 1 11 (1				

Diode-inverter

Absolute Maximum Ratings

Parameter	Symbol	Conditions	Value	Unit
- OOOQ + F- QNN1 GB	1--(	/QE ℃		1
IODP PN NR M PNNIO				
- OOOQ + F NR M PNNIO	-(	O HN		
OQ GP	O	1. 1O HN/GE ℃		N
		1. 1O HN/GE ℃		

Characteristic Values

Parameter	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
NR M1 GB	1	/GE ℃				1
		/GE ℃				
		/GE ℃				
- QM CNB	, NN	1. 1 D O PN /GE ℃				P
+ F- QNN - QNT PNNIO	NN					
- QNN - QNT I NBT	N					H
- QM CNB	, NN	1. 1 D O PN /GE ℃				P
+ F- QNN - QNT PNNIO	NN					
- QNN - QNT I NBT	N					H

IGBT-brake-chopper

Absolute Maximum Ratings

Parameter	Symbol	Conditions	Value	Unit
G OM HDDM GB	1 .	1 1 H /E ℃		1
IDP PN G OM PWM IO		/ ℃ TEH S= ℃		
- DD + F G OM PWM IO	-(	O HN		
O HDDM GB	1 .	/E ℃	±	1
/ OG+ R M DND DI	+OO	/ ℃ /EH S ℃		2

Characteristic Values

Parameter	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
O HDDM/CMNC G1 GB	1 C	1 1 H /E ℃				1
G OM HDDM PO AA PWM IO	.	1 11 1 /E ℃				H
G OM HDDM . PMDI 1 GB	1 NO	1 1 /E ℃				1
		1 1 /E ℃				
		1 1 /E ℃				
O C NB	,					P
I PO DI	DN	1 11 1 A (U /E ℃				I
- QM /MINAM DI	MN					I
O HDDMG F B PWM IO	.	1 11 1 /E ℃				I
/PM I GT/DH	O I	1 1 1 1 - /E ℃				IN
-DN /DH	QM					IN
/PM AA GT/DH	O AA					IN
GT/DH	QA					IN
I NBT DND DI PMDB /PM I /DH	I					H
I NBT DND DI PMDB /PM AA/DH	AA					H

/PM I GT/DH	O I					IN
-DN /DH	QM					IN
/PM AA GT/DH	O AA	1 1				IN
GT/DH	QA	1 1 -				IN
I NBT DND ODI PMDB /PM I /DH	I	/CE ℃				H
I NBT DND ODI PMDB /PM AA/DH	AA					H
. O	.	O PN1 1 /CE ℃ 1 11 (1				

● Diode-brake-chopper

Absolute Maximum Ratings

Parameter	Symbol	Conditions	Value	Unit
- ODDQ + F- QMN1 GB	1 -(	/CE ℃		1
IODP PN NR M PMMIO				
- ODDQ + F NR M PMMIO	-(	O HN		
OQ GP	O	1. 1O HN/CE ℃		N
		1. 1O HN/CE ℃		

Characteristic Values

Parameter	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
NR M1 GB	1	/CE ℃				1
		/CE ℃				
		/CE ℃				
- QM CNB	, MM					P
+ F- QMN - QMT PMMIO	MM	1. 1 DO PN /CE ℃				
- QMN - QMT I NBT	M					H
- QM CNB	, MM					P
+ F- QMN - QMT PMMIO	MM	1. 1 DO PN /CE ℃				
- QMN - QMT I NBT	M					H

Diode-rectifier

Absolute Maximum Ratings

Parameter	Symbol	Conditions	Value	Unit
- ODDQ + F- QMN 1 GB	1--(	/E ℃		1
QMB POPO PMMIO UND RQ	1	/ ℃		
(SDHPH -(. PMMIO O - ODADM POPO	-(.(	/ ℃		
.PMB NR M PMMIO	.(	1. 1O HN/E ℃		
OQGP	O	1. 1O HN/E ℃		N

Characteristic Values

Parameter	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
D NR M1 GB	1	/E ℃				1
- QMN PMMIO	-	/E ℃1. 1				H

NTC-Thermistor

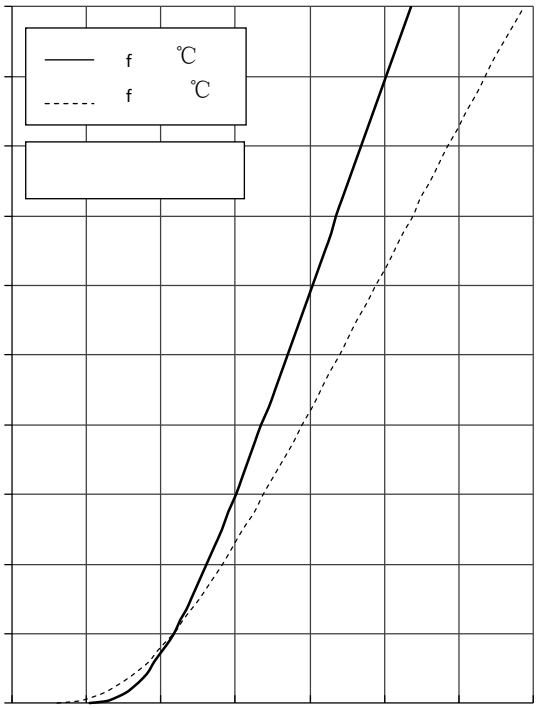
Characteristic Values

Parameter	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
- O - NDOI	-					F
QDODI A-	- -	/ ℃-				
+ R M DND ODI	+					H2
QGP		- - S6 / &8				&

Module Characteristics

T_C=25°C unless otherwise specified

Parameter	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
N GDDI 1 GB	1 DNG	O HDA U				1
(SBHPH PI ODI / H MOPM	/EH S					℃
MODB PI ODI / H MOPM	/CE					℃
. OMB / H MOPM	/NB					℃
. OMTD P OI H PG	.					nH
(PG G MNDDOI OMHD GN CD	-	/ ℃ MRDDC				m
	-					
/C MH G- NDDOI PI ODI O N	-	M / DQ MOM				&2
		M D DQ MOM				
		M / =MF C M				
		M D C M				
		M D M ODA M				
/C MH G- NDDOI N O. DF	- .	M / DQ MOM				&2
		M D DQ MOM				
		M / =MF C M				
		M D C M				
		M D M ODA M				
		M(PG				
(PI ODB M + M GH						)
2 DBOO A(PG						B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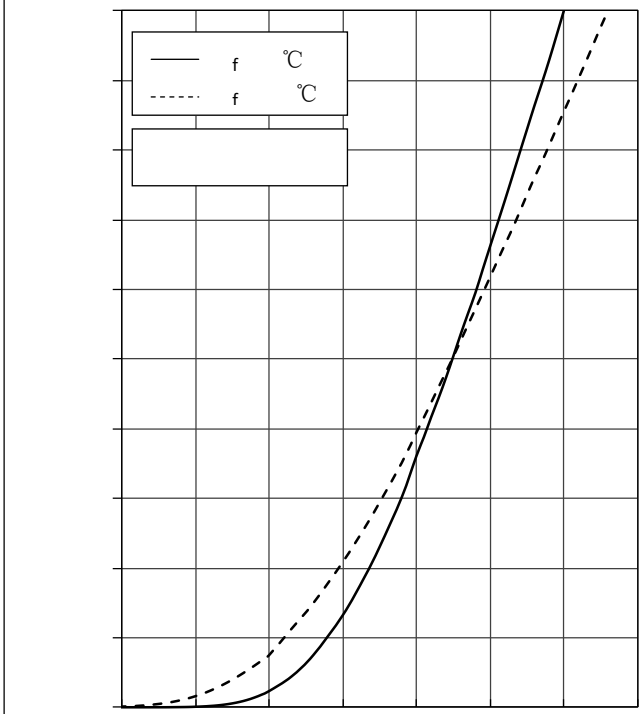
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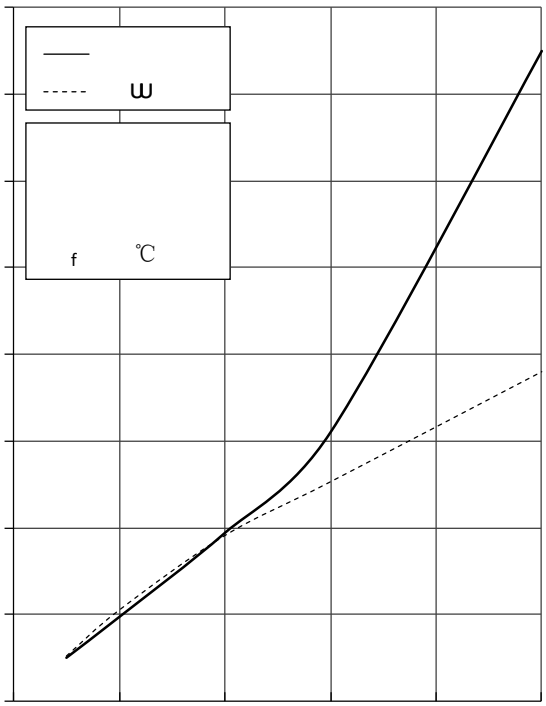
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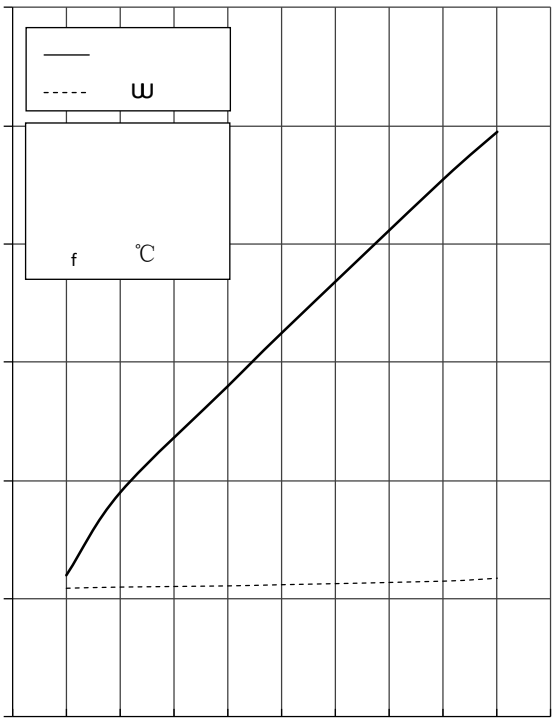
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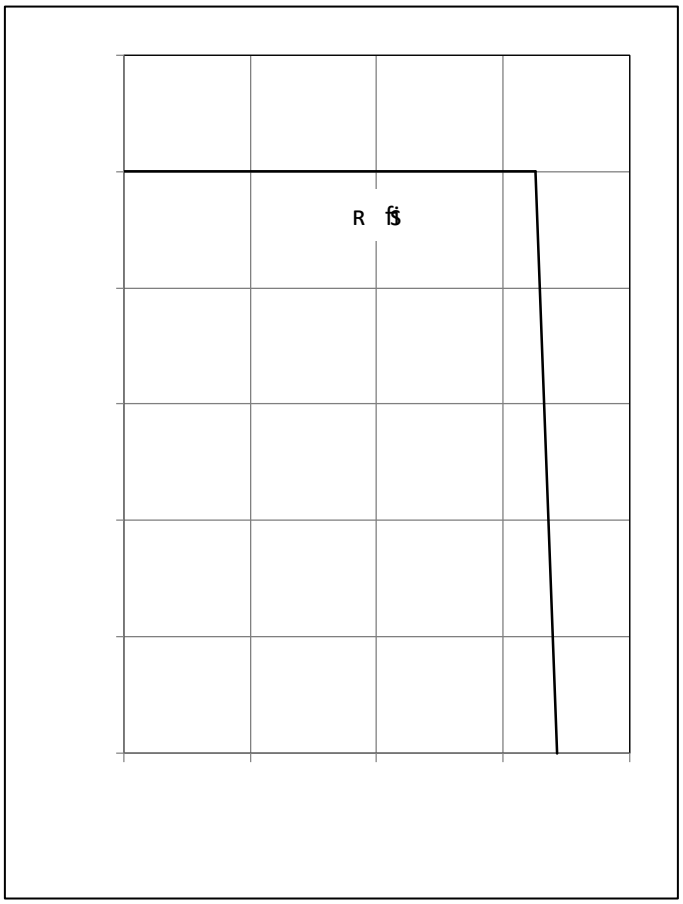

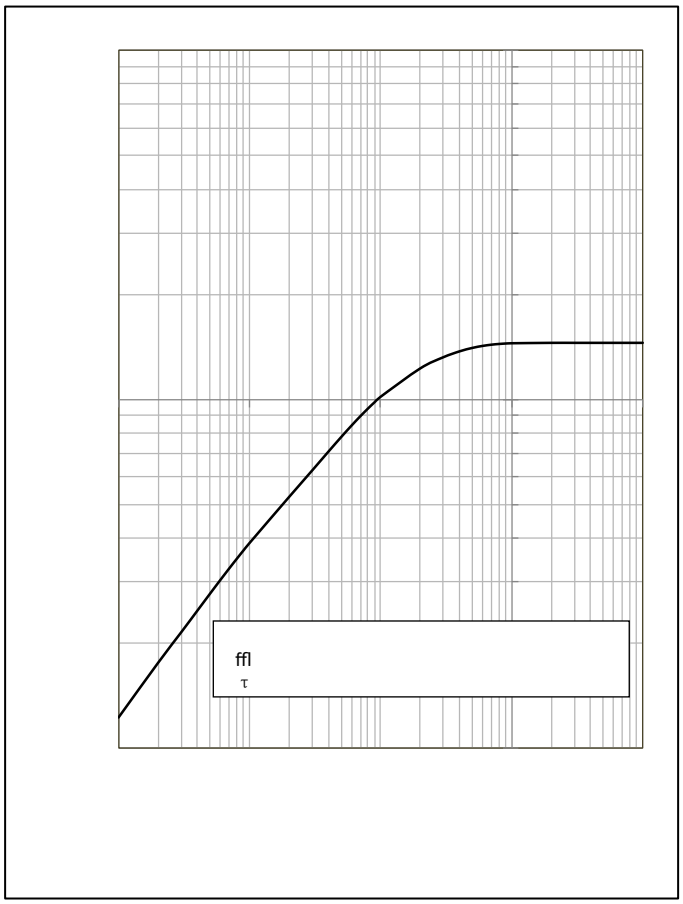

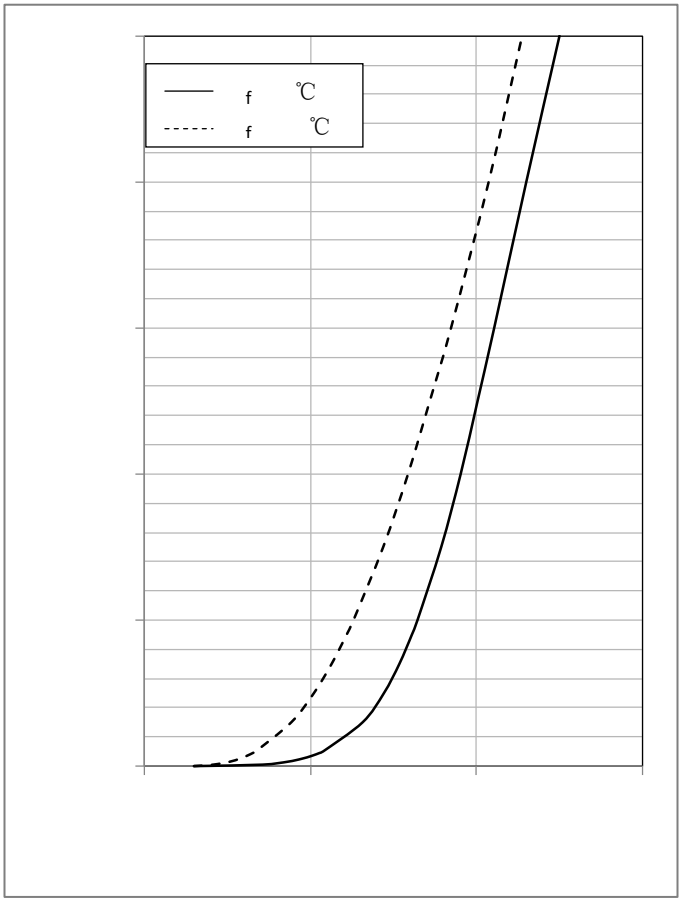

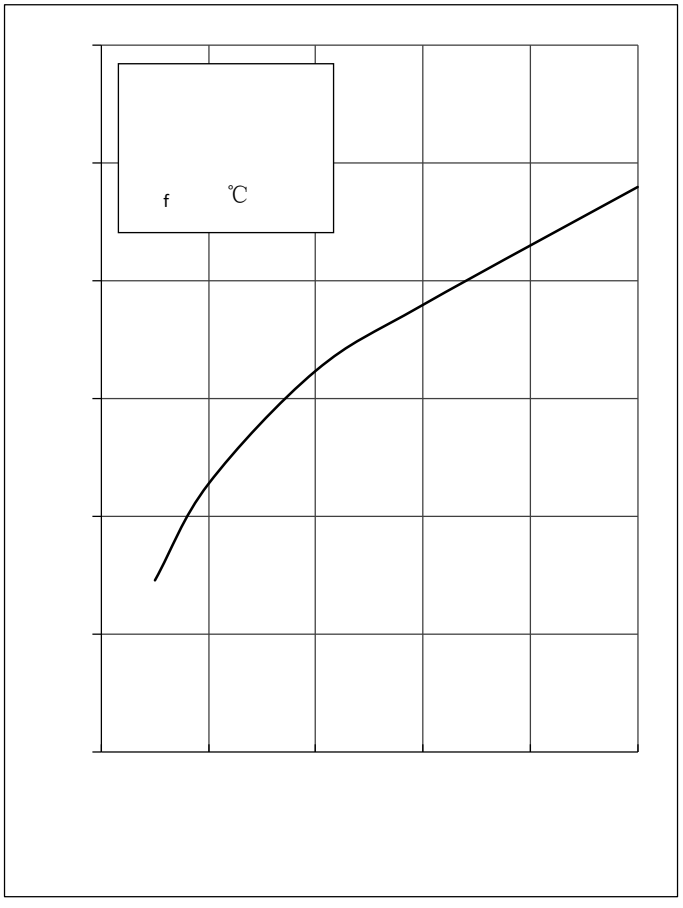

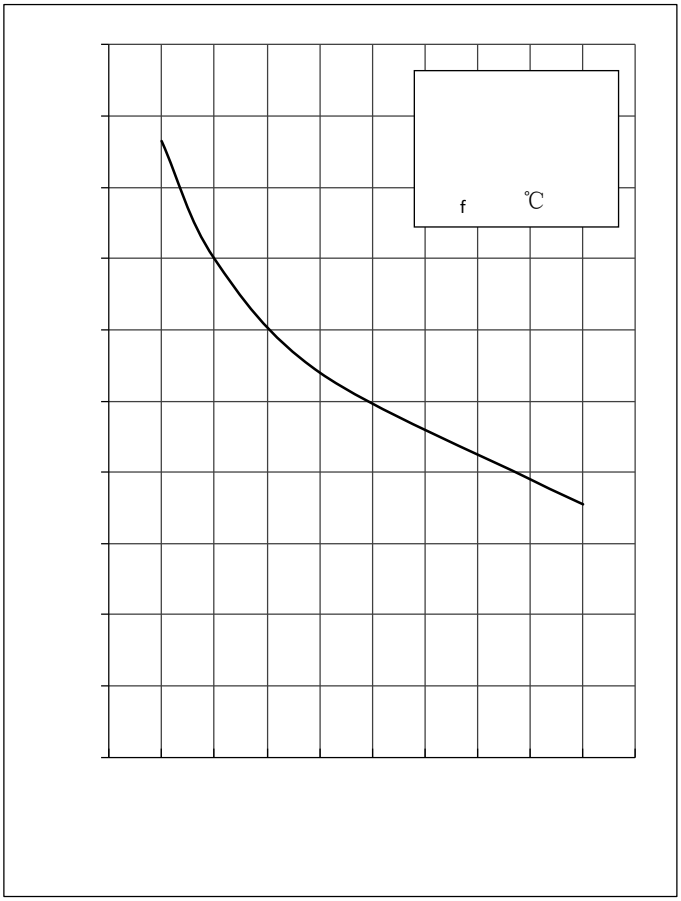
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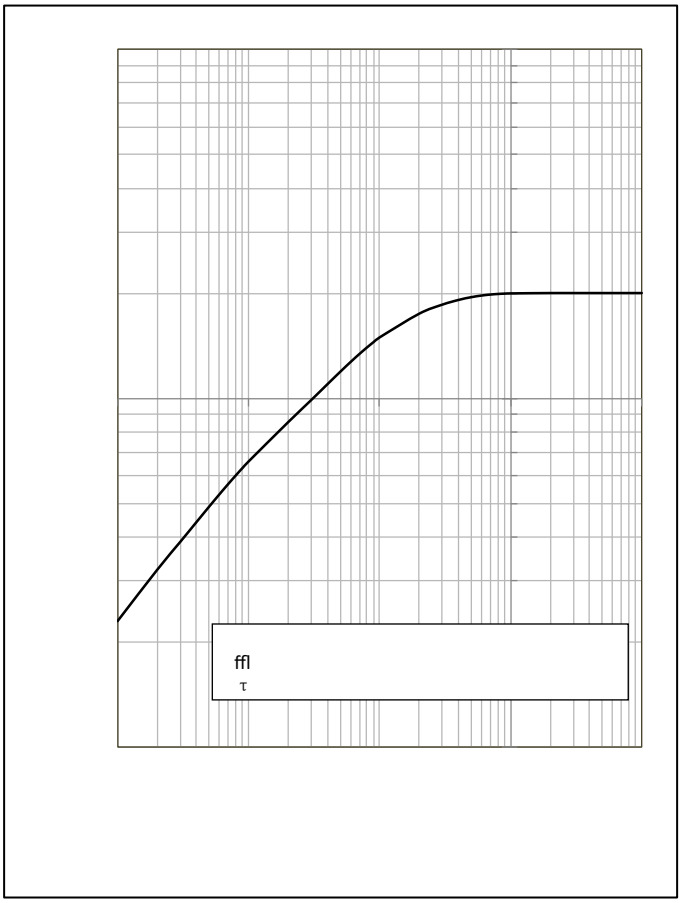
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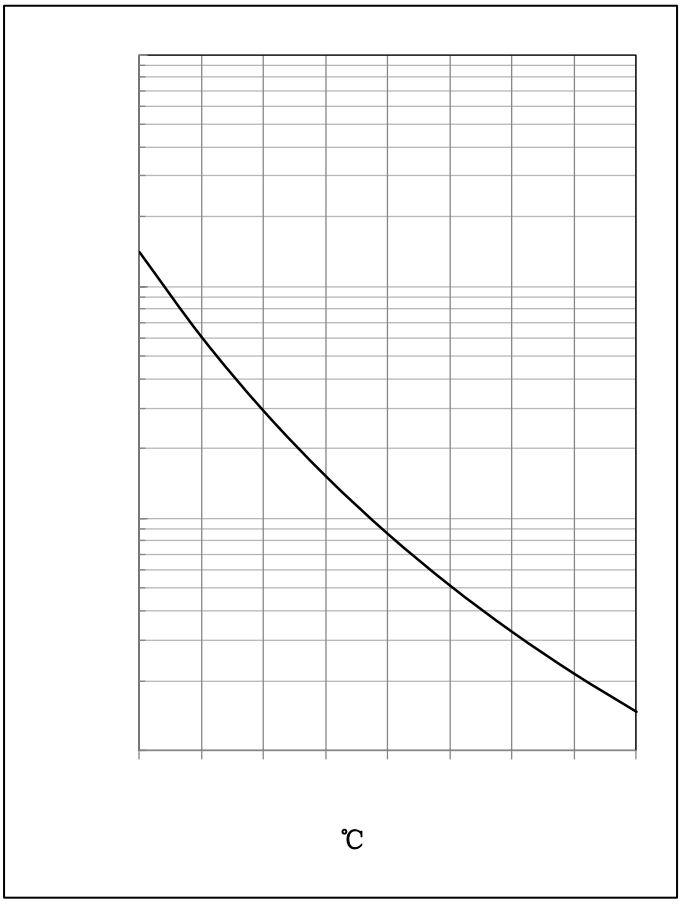
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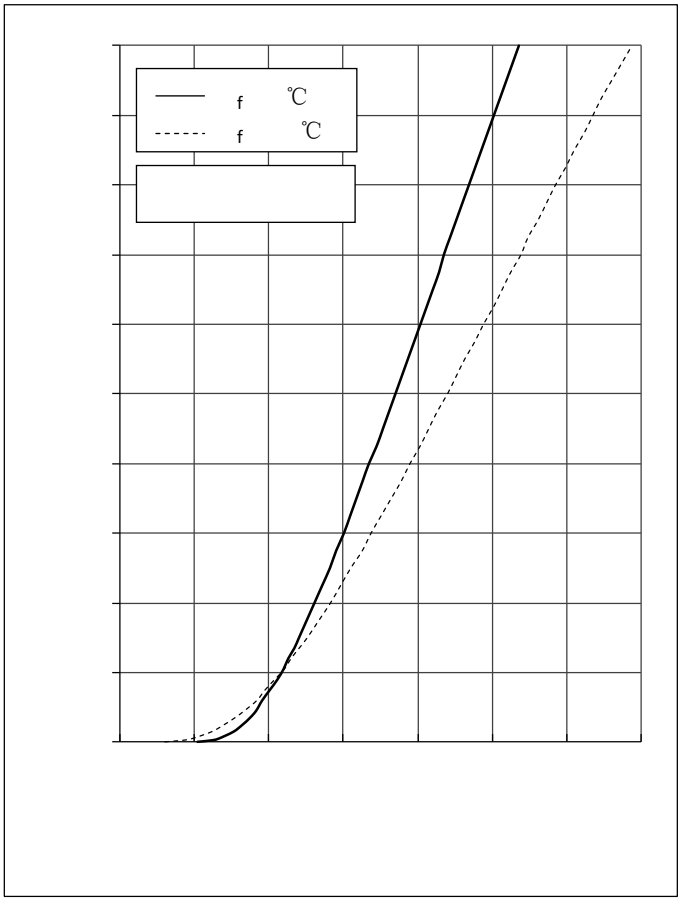
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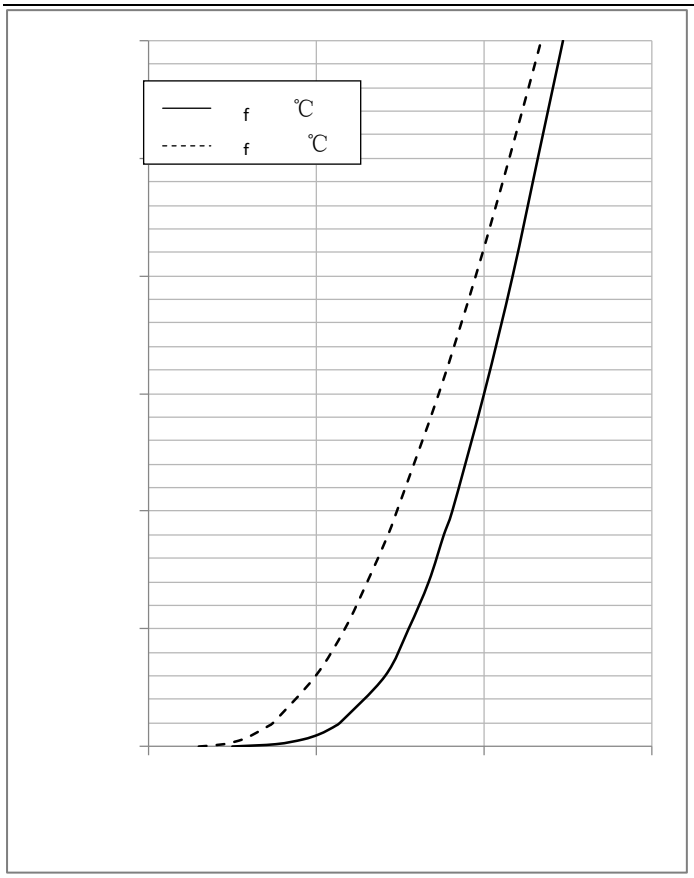
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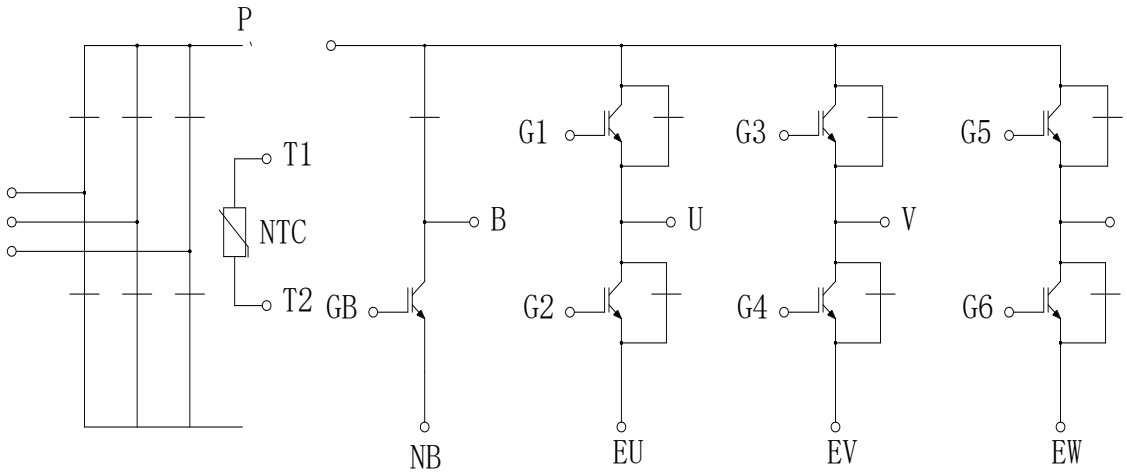
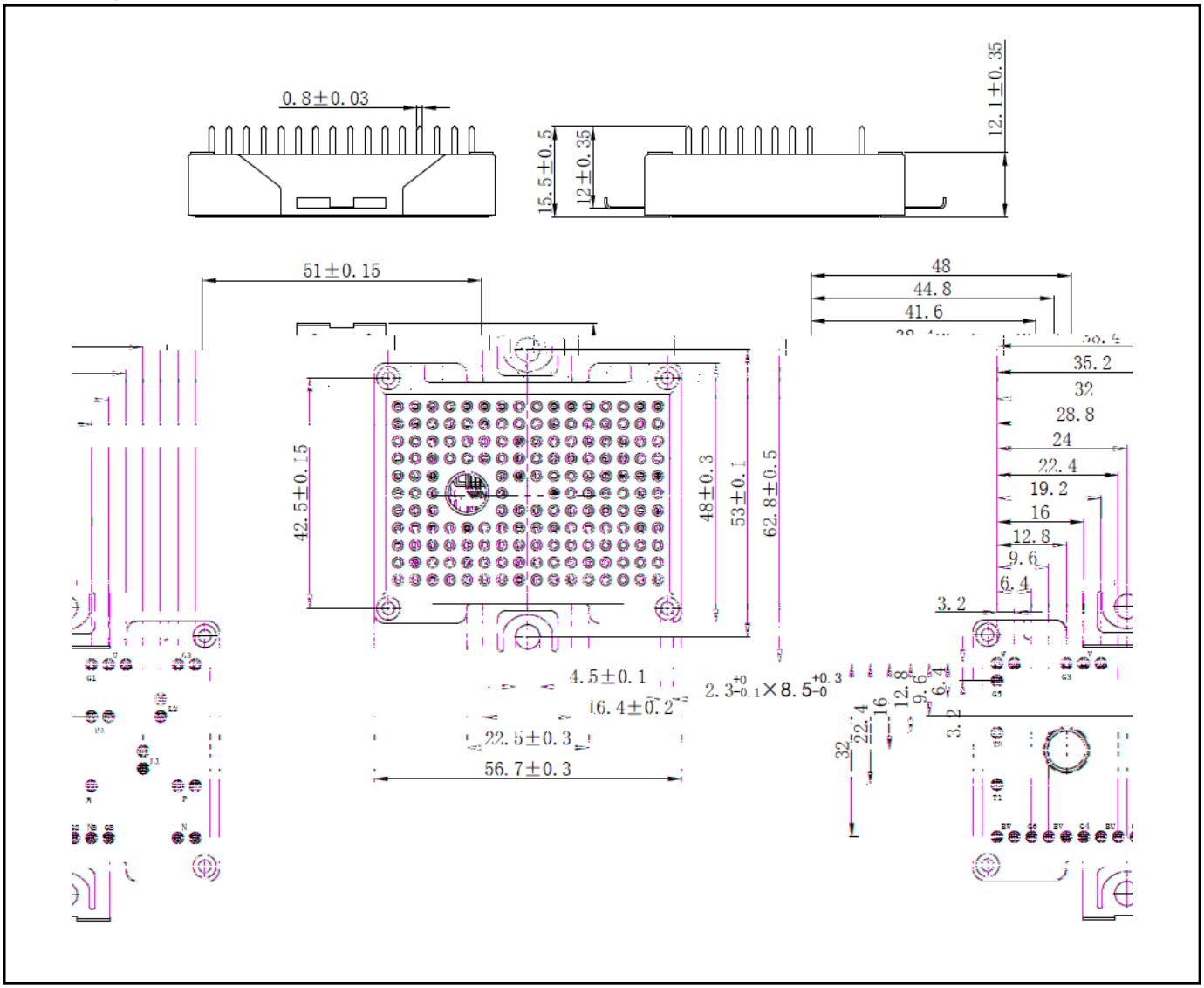
Circuit Diagram



- **Package Dimensions**



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